

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

ON Semiconductor NSS20200W6T1G

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>



Distributor of ON Semiconductor: Excellent Integrated System Limited Datasheet of NSS20200W6T1G - TRANS PNP 20V 2A SC-88 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

NSS20200W6

20 V, 3.0 A, Low V_{CE(sat)} **PNP Transistor**

ON Semiconductor's e²PowerEdge family of low V_{CE(sat)} transistors are miniature surface mount devices featuring ultra low saturation voltage (V_{CE(sat)}) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

• This is a Pb-Free Device

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Мах	Unit
Collector-Emitter Voltage	V _{CEO}	-20	Vdc
Collector-Base Voltage	V _{CBO}	-20	Vdc
Emitter-Base Voltage	V _{EBO}	-7.0	Vdc
Collector Current – Continuous	Ι _C	-2.0	А
Collector Current – Peak	I _{CM}	-3.0	A

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$	P _D (Note 1)	426	mW
Derate above 25°C		3.4	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 1)	293	°C/W
Total Device Dissipation $T_A = 25^{\circ}C$	P _D (Note 2)	555	mW
Derate above 25°C		4.4	m₩/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 2)	225	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

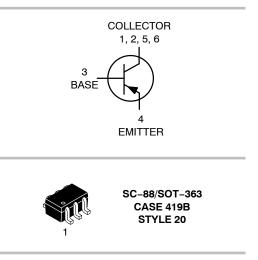
1. FR-4 @ 100 mm², 1 oz. copper traces. 2. FR-4 @ 500 mm², 1 oz. copper traces.



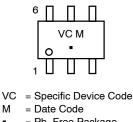
ON Semiconductor®

http://onsemi.com

-20 VOLTS, 3.0 AMPS PNP LOW $V_{CE(sat)}$ TRANSISTOR EQUIVALENT $R_{DS(on)}$ 65 m Ω



DEVICE MARKING



= Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping †
NSS20200W6T1G	SC-88 (Pb-Free)	3000/ Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.



NSS20200W6

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_C = -10 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	-20	-	-	Vdc
Collector – Base Breakdown Voltage $(I_C = -0.1 \text{ mAdc}, I_E = 0)$	V _{(BR)CBO}	-20	-	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = -0.1 \text{ mAdc}, I_C = 0)$	V _{(BR)EBO}	-7.0	-	-	Vdc
Collector Cutoff Current ($V_{CB} = -20$ Vdc, $I_E = 0$)	I _{СВО}	_	-	-0.1	μAdc
Emitter Cutoff Current (V _{EB} = -7.0 Vdc)	I _{EBO}	_	-	-0.1	μAdc
ON CHARACTERISTICS			•	•	
$ \begin{array}{l} \text{DC Current Gain (Note 3)} \\ (I_{C} = -10 \text{ mA}, \text{ V}_{CE} = -2.0 \text{ V}) \\ (I_{C} = -500 \text{ mA}, \text{ V}_{CE} = -2.0 \text{ V}) \\ (I_{C} = -1.0 \text{ A}, \text{ V}_{CE} = -2.0 \text{ V}) \\ (I_{C} = -2.0 \text{ A}, \text{ V}_{CE} = -2.0 \text{ V}) \end{array} $	h _{FE}	250 220 200 160	370 325 290 245		
	V _{CE(sat)}	- - - -	-0.010 -0.067 -0.102 -0.128 -0.177	-0.014 -0.092 -0.126 -0.165 -0.215	V
Base – Emitter Saturation Voltage (Note 3) ($I_C = -1.0 \text{ A}, I_B = -0.01 \text{ A}$)	V _{BE(sat)}	_	_	-0.900	V
Base – Emitter Turn–on Voltage (Note 3) $(I_C = -1.0 \text{ A}, V_{CE} = -2.0 \text{ V})$	V _{BE(on)}	_	_	-0.900	V
Cutoff Frequency (I _C = -100 mA, V _{CE} = -5.0 V, f = 100 MHz)	f _T	100	-	_	MHz
Input Capacitance (V _{EB} = -0.5 V, f = 1.0 MHz)	Cibo	-	-	330	pF
Output Capacitance (V _{CB} = -3.0 V, f = 1.0 MHz)	Cobo	-	-	90	pF
SWITCHING CHARACTERISTICS					
Delay (V _{CC} = -10 V, I _C = 750 mA, I _{B1} = 15 mA)	t _d	-	-	65	ns
Rise (V _{CC} = -10 V, I _C = 750 mA, I _{B1} = 15 mA)	tr	-	-	100	ns
Storage (V _{CC} = -10 V, I _C = 750 mA, I _{B1} = 15 mA)	t _s	-	-	320	ns
Fall (V _{CC} = -10 V, I _C = 750 mA, I _{B1} = 15 mA)	t _f	-	-	125	ns

3. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle $\leq 2\%$.

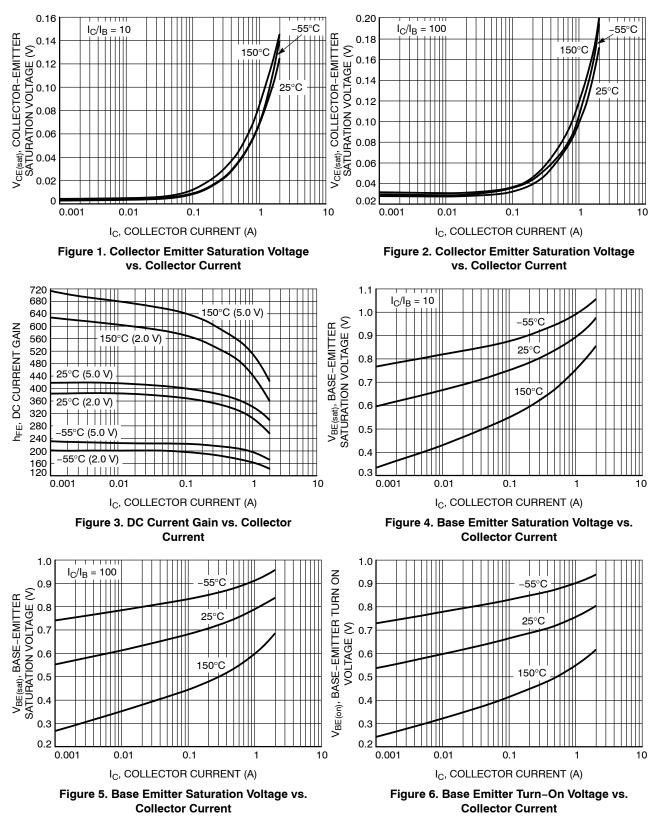
4. Guaranteed by design but not tested.



Distributor of ON Semiconductor: Excellent Integrated System Limited Datasheet of NSS20200W6T1G - TRANS PNP 20V 2A SC-88 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

NSS20200W6

TYPICAL CHARACTERISTICS

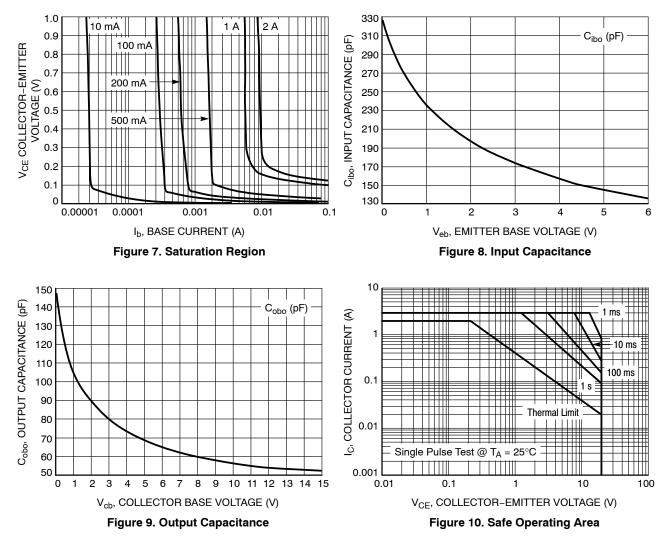




Distributor of ON Semiconductor: Excellent Integrated System Limited Datasheet of NSS20200W6T1G - TRANS PNP 20V 2A SC-88 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

NSS20200W6

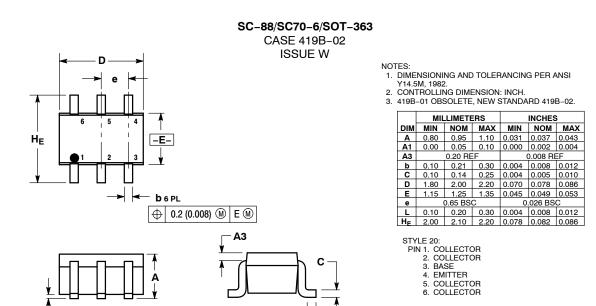
TYPICAL CHARACTERISTICS





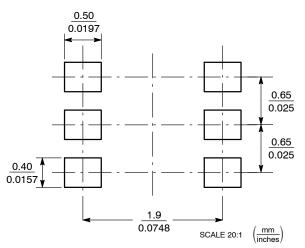
NSS20200W6

PACKAGE DIMENSIONS



SOLDERING FOOTPRINT*

L.



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and
are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer applications can and do vary in different applications contoner on convey any license under its patern rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

Α1

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5773–9850 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

NSS20200W6/D